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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/797,046	03/11/2004	Jung-hyun Lee	2557SI-001239/US	4688
	7590 04/07/201 CKEY & PIERCE, P.L		EXAMINER	
P.O. BOX 8910 RESTON, VA 20195			NADAV, ORI	
RESTON, VA	20193		ART UNIT	PAPER NUMBER
			2811	
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)	
	10/797,046	LEE ET AL.	
Office Action Summary	Examiner	Art Unit	
	Ori Nadav	2811	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet w	rith the correspondence addr	ess
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNI 136(a). In no event, however, may a will apply and will expire SIX (6) MO e, cause the application to become A	CATION. reply be timely filed NTHS from the mailing date of this common BANDONED (35 U.S.C. § 133).	
Status			
 1) Responsive to communication(s) filed on 14 M 2a) This action is FINAL. 2b) This 3) Since this application is in condition for allowed closed in accordance with the practice under the condition of the condition of	s action is non-final. ance except for formal mat	· •	nerits is
Disposition of Claims			
4) ☑ Claim(s) 22 and 23 is/are pending in the appli 4a) Of the above claim(s) is/are withdra 5) ☐ Claim(s) is/are allowed. 6) ☑ Claim(s) 22 and 23 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or	awn from consideration.		
Application Papers			
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the E	cepted or b) objected to drawing(s) be held in abeya ction is required if the drawing	nce. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR	, ,
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documen 2. Certified copies of the priority documen 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	its have been received. Its have been received in A prity documents have beer au (PCT Rule 17.2(a)).	Application No n received in this National St	tage
Attachment(s)	_		
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	Paper No	Summary (PTO-413) (s)/Mail Date Informal Patent Application 	

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DETAILED ACTION

Claim Objections

Claim 22 is objected to because of the following informalities: The phrase "am upper" should read "an upper". Appropriate correction is required.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 22 is rejected under 35 U.S.C. 103(a) as being unpatentable over Cabral Jr. et al. (6,982,230) in view of Seidl et al. (2002/0014647) and Chang et al. (3,996,021). Cabral Jr. et al. teach in figure 29 and related text a capacitor of a semiconductor device, the capacitor comprising:

- a lower electrode 33 formed on a semiconductor substrate 30;
- a first dielectric film 34 formed on the lower electrode;
- an upper electrode 35 formed on the first dielectric film; and
- a second dielectric film 34 (see column 14, lines 45-47) between the upper electrode and the film,

wherein the second dielectric film is an HfO₂ layer, a ZrO₂ layer, or an STO layer, and

wherein the second dielectric film is directly in contact with the upper electrode. Cabral Jr. et al. do not teach using an AHO ($(AI_x,Hf_{1-x})O_y$) film as the first dielectric film. Seidl et al. teach in figure 1n and related text a capacitor comprising a lower electrode 60, an AHO ($(AI_x,Hf_{1-x})O_y$) film 70 formed directly on the lower electrode, and an upper electrode 80 formed on the AHO ($(AI_x,Hf_{1-x})O_y$) film.

Chang et al. teach the advantages of using an AHO ($(AI_x, Hf_{1-x})O_y$) film (column 6, lines 33-50).

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to replace the first dielectric film in Cabral Jr. et al.'s device with an AHO $((Al_x,Hf_{1-x})O_y)$ film, as taught by Seidl et al., in order to improve the device characteristics.

The combination is motivated by the teachings of Chang et al. who point out the advantages of using an AHO ($(Al_x, Hf_{1-x})O_y$) film (column 6, lines 33-50).

Note that substitution of materials is not patentable even when the substitution is new and useful. Safetran Systems Corp. v. Federal Sign & Signal Corp. (DC NIII, 1981) 215 USPQ 979.

Note further that the combined device includes a second dielectric film having a dielectric constant that is higher than that of the second dielectric film.

Claim 23 is rejected under 35 U.S.C. 103(a) as being unpatentable over Cabral Jr. et al. and Chang et al. and Seidl et al., as applied to claim 22 above, and further in view of Chooi et al. (6,486,080).

Cabral Jr. et al., Chang et al. and Seidl et al. teach substantially the entire claimed structure, as applied to claim 22 above, except an oxidation barrier film formed between the lower electrode and the AHO ((Al_x,Hf_{1-x})O_y) film.

Chooi et al. teach an oxidation barrier film formed between the lower electrode and the AHO ($(AI_x,Hf_{1-x})O_y$) film (column 2, lines 16-20).

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use an oxidation barrier film formed between the lower electrode and the AHO ((AI_x,Hf_{1-x})O_y) film in prior art's device, in order to improve the device characteristics.

Response to Arguments

Applicants argue that "one of ordinary skill in the art would not have been motivated to modify Cabral's capacitor to include the AHO layer of Chang, because Chang's AHO film would be used to coat a metal article in Cabral, which is not suggested because the technical field of Cabral is not related to coating a metal article".

Chang et al. was not cited to motivate an artisan "to modify Cabral's capacitor to include the AHO layer of Chang", as argued by applicants. Chang et al. was cited to teach an artisan the advantages of using an AHO $((AI_x, Hf_{1-x})O_y)$ material versus other materials. Seidl et al., on the other hand, was cited to motivate an artisan to replace the inferior dielectric material in Cabral Jr. et al.'s device with an AHO $((AI_x, Hf_{1-x})O_y)$ material.

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Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ori Nadav whose telephone number is 571-272-1660. The examiner can normally be reached between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Lynne Gurley can be reached on 571-272-1670. The fax phone number for

the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent

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O.N. 4/7/2011 /ORI NADAV/ PRIMARY EXAMINER TECHNOLOGY CENTER 2800